

TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

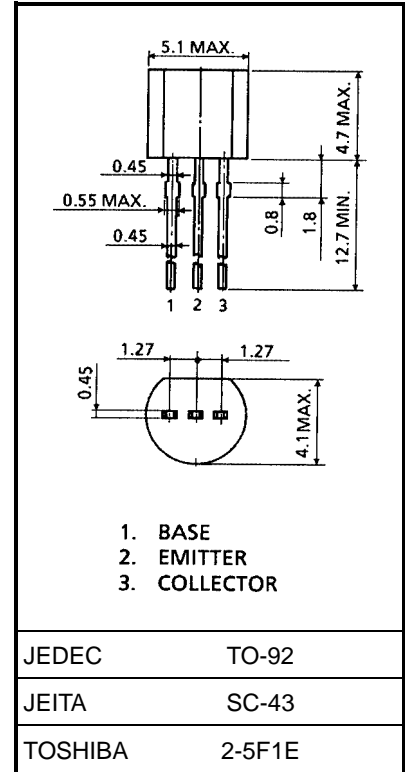
2SC2498

VHF~UHF Band Low Noise Amplifier Application

Unit: mm

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CB0}	30	V
Collector-emitter voltage	V _{CEO}	20	V
Emitter-base voltage	V _{EBO}	3	V
Collector current	I _C	50	mA
Base current	I _B	25	mA
Collector power dissipation	P _C	300	mW
Junction temperature	T _j	125	°C
Storage temperature range	T _{stg}	-55~125	°C



Weight: 0.21 g (typ.)

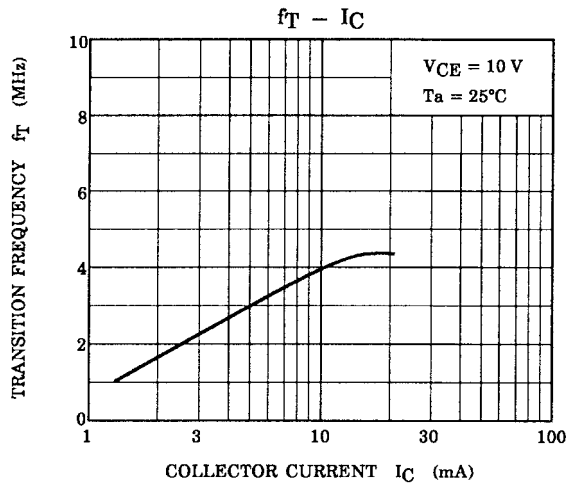
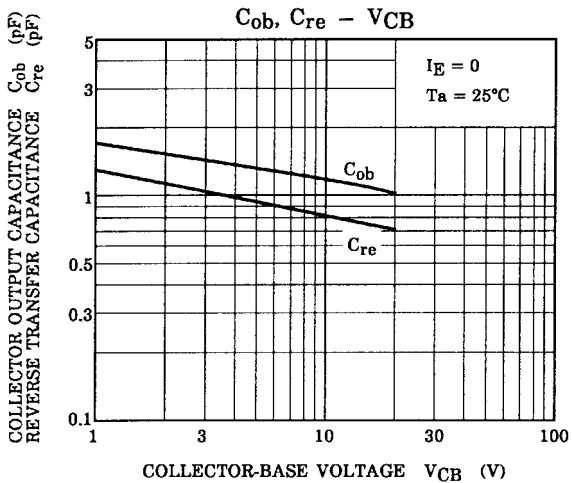
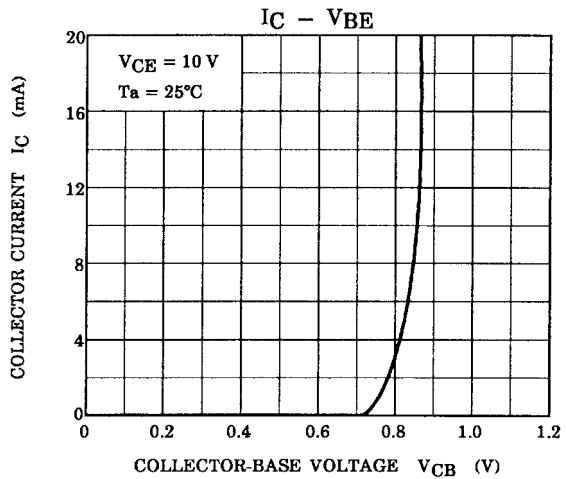
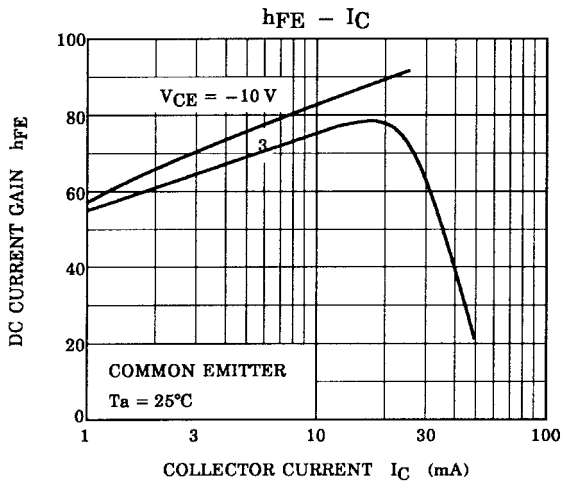
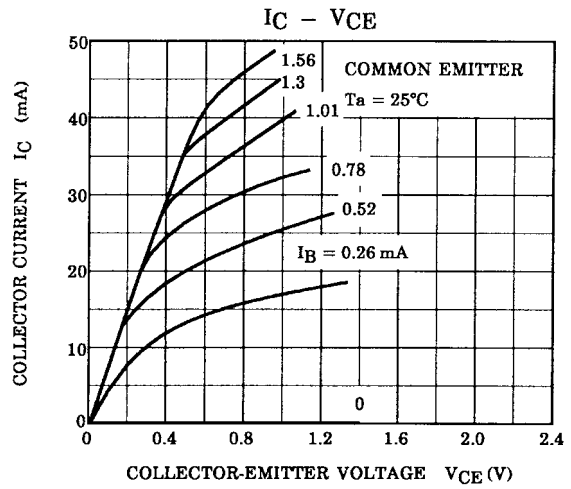
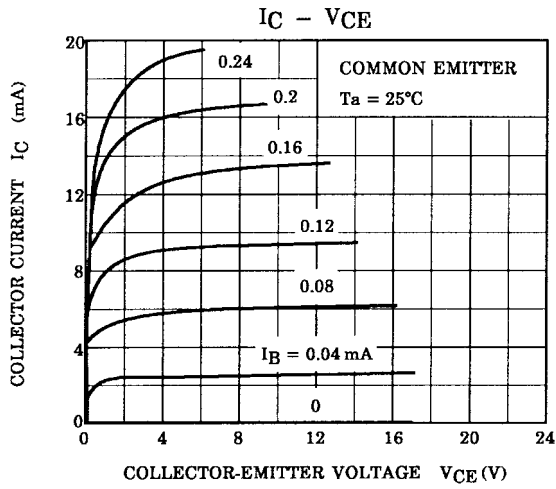
Microwave Characteristics (Ta = 25°C)

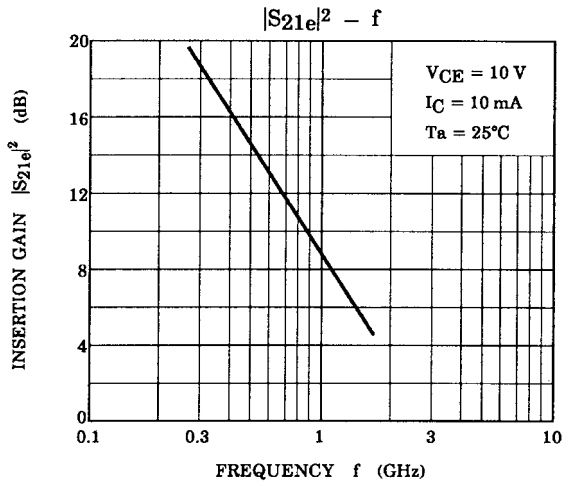
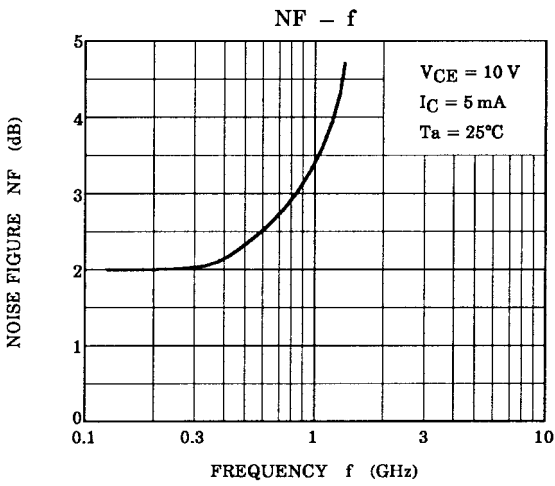
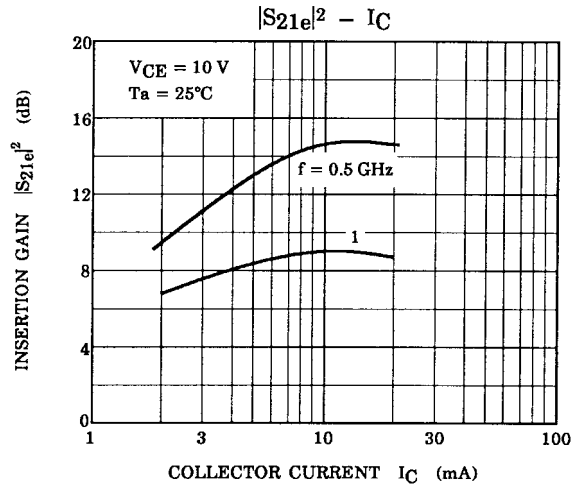
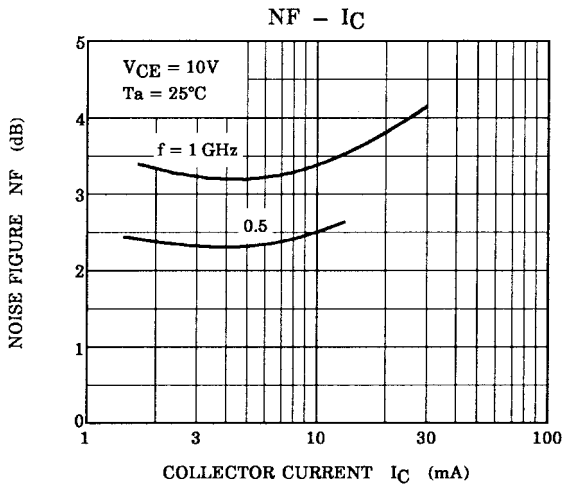
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Transition frequency	f _T	V _{CE} = 10 V, I _C = 10 mA	—	3.5	—	GHz
Insertion gain	S _{21e} ² (1)	V _{CE} = 10 V, I _C = 10 mA, f = 500 MHz	—	14.5	—	dB
	S _{21e} ² (2)	V _{CE} = 10 V, I _C = 10 mA, f = 1 GHz	—	9	—	
Noise figure	NF (1)	V _{CE} = 10 V, I _C = 5 mA, f = 500 MHz	—	2.5	—	dB
	NF (2)	V _{CE} = 10 V, I _C = 5 mA, f = 1 GHz	—	4	—	

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I _{CB0}	V _{CB} = 10 V, I _E = 0	—	—	1	μA
Emitter cut-off current	I _{EBO}	V _{EB} = 1 V, I _C = 0	—	—	1	μA
DC current gain	h _{FE}	V _{CE} = 10 V, I _C = 10 mA	30	80	300	
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz (Note)	—	1.15	—	pF
Reverse transfer capacitance	C _{re}		—	0.75	—	pF

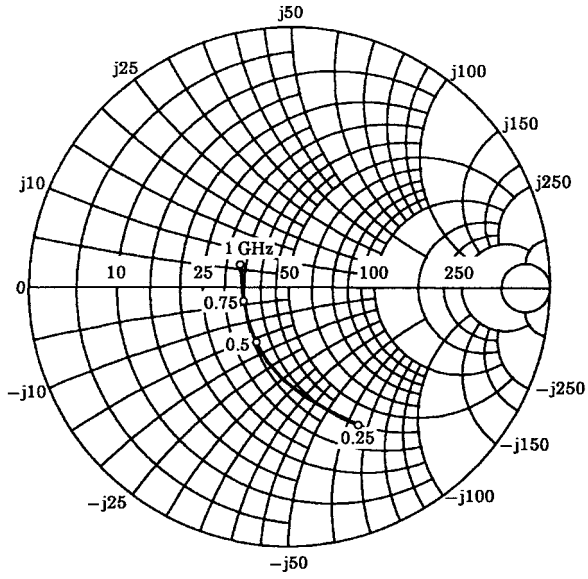
Note: C_{re} is measured by 3 terminal method with capacitance bridge.



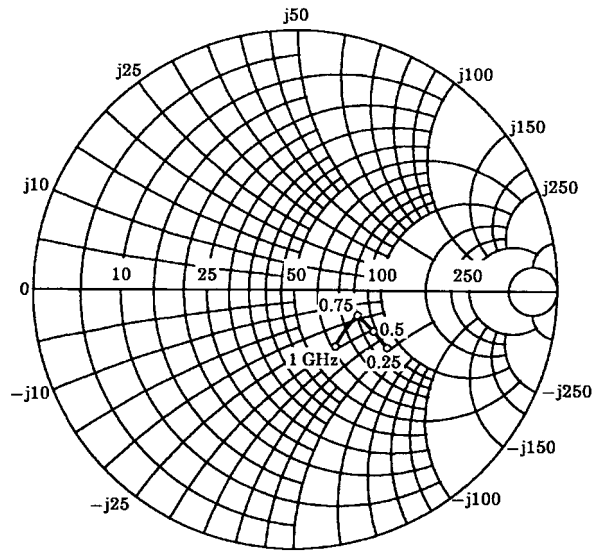


Common Emitter Small Signal S-Parameters of 2SC2498.

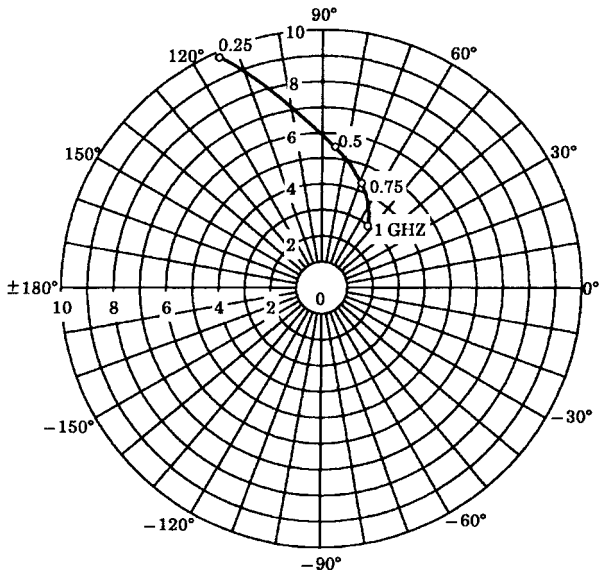
$V_{CE} = 10\text{ V}$, $I_C = 10\text{ mA}$



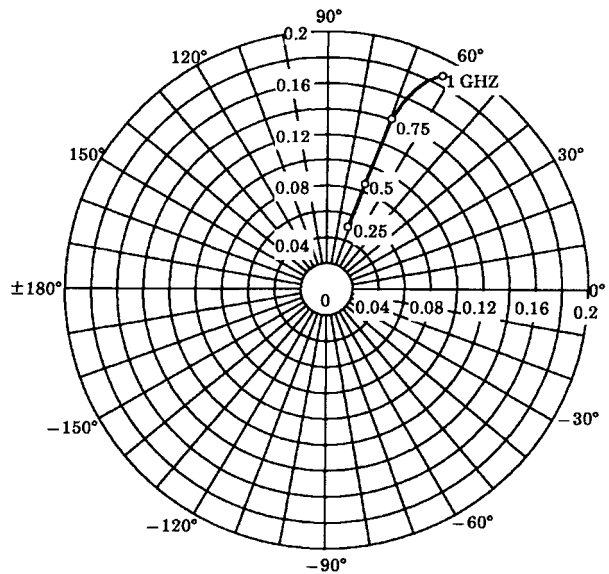
S_{11e} (UNIT : Ω)



S_{22e} (UNIT : Ω)



S_{21e}



S_{12e}

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